

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

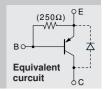
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Built-in Diode at C-E 2SA1568 Low Vce (sat)



Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC4065)

Application: DC Motor Driver, Chopper Regulator and General Purpose

Absolute maximum ratings (1a=25°C)							
Symbol	Ratings	Unit					
Vсво	-60	V					
VCEO	-60	V					
VEBO	-6	V					
Ic	∓ 12	Α					
lв	-3	Α					

35(Tc=25°C)

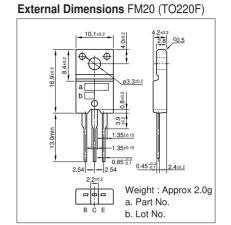
-55 to +150

Pc

Τj

Tstg

■Electrical Cl	naracteristics	(Ta=25°C)		
Symbol	Conditions	Ratings	Unit	
Ісво	Vcb=-60V	-100max	μΑ	
ГЕВО	VEB=-6V	-60max	mA	
V(BR)CEO	Ic=-25mA	-60min	V	
hfE	Vce=-1V, Ic=-6A	50min		
VcE(sat)	Ic=-6A, IB=-0.3A	-0.35max	V	
VFEC	IECO=-10A	-2.5max	V	
f⊤	Vce=-12V, IE=0.5A	40typ	MHz	
Сов	VcB=-10V, f=1MHz	330typ	pF	



■Typical Switching Characteristics (Common Emitter)

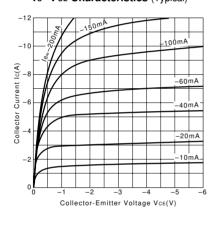
W

°C

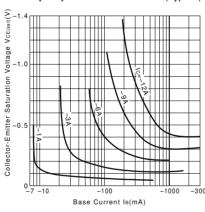
°C

Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (mA)	I _{B2} (mA)	ton (µs)	tstg (µs)	tf (μs)		
-24	4	-6	-10	5	-120	120	0.4typ	0.4typ	0.2typ		

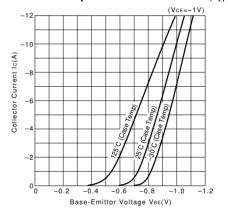
Ic-VcE Characteristics (Typical)



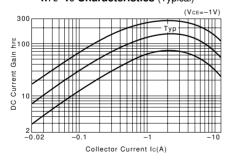
VcE(sat)-IB Characteristics (Typical)



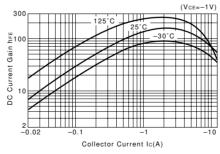
Ic-VBE Temperature Characteristics (Typical)



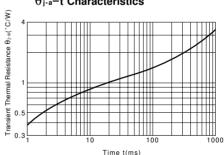
hfe-Ic Characteristics (Typical)



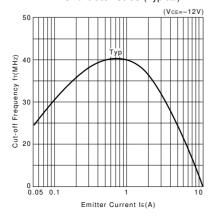
hfe-Ic Temperature Characteristics (Typical)



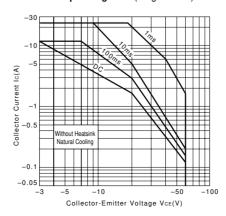
θ_{j-a}-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

